QUADRUPLE 2-LINE TO 1-LINE DATA SELECTORS/MULTIPLEXERS

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- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-833, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

These quadruple 2-line to 1-line data selectors/multiplexers are designed for 2-V to 5.5-V V_{CC} operation.

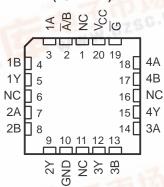
The 'AHC157 devices feature a common strobe (\overline{G}) input. When the strobe is high, all outputs are low. When the strobe is low, a 4-bit word is selected from one of two sources and is routed to the four outputs. The devices provide true data.

The SN54AHC157 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHC157 is characterized for operation from –40°C to 85°C.

SN54AHC157 . . . J OR W PACKAGE SN74AHC157 . . . D, DB, DGV, N, OR PW PACKAGE (TOP VIEW)

Ā/B [1	U	16	V _{CC}
1A [2		15] G
1B [3		14] 4A
1Y [4		13] 4B
2A [5		12] 4Y
2B [6		11] 3A
2Y [7		10] 3B
GND [8		9] 3Y

SN54AHC157 . . . FK PACKAGE (TOP VIEW)



NC – No internal connection

FUNCTION TABLE

F-5.	INPL	OUTPUT		
G	A/B	Α	В	Y
Н	Х	Χ	Χ	L
L	L	L	Χ	L
L	L	Н	Χ	Н
L	Н	Χ	L	- L
L	Н	X	Н	Н

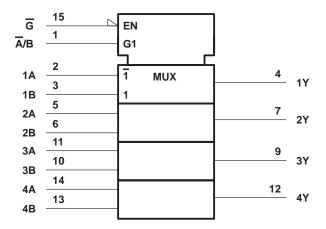
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





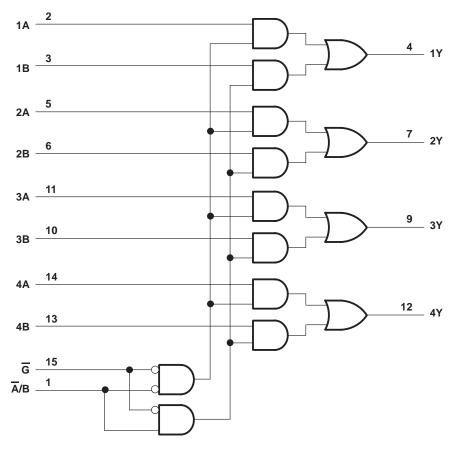
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logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (see Note 1)		
Output voltage range, VO (see Note 1)		\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)		—20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CO}$	c)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ _{JA} (see Note 2):	: D package	73°C/W
	DB package	82°C/W
	DGV package	120°C/W
	N package	67°C/W
	PW package	108°C/W
Storage temperature range, T _{stq}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions (see Note 3)

			SN54A			SN74AHC157		
			MIN	MAX	MIN	MAX	UNIT	
Vcc	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
ViH	High-level input voltage	V _{CC} = 3 V	2.1		2.1		V	
		V _{CC} = 5.5 V	3.85		3.85			
		V _{CC} = 2 V		0.5		0.5		
VIL	Low-level input voltage	V _{CC} = 3 V		0.9		0.9	V	
	V	V _{CC} = 5.5 V	T	1.65		1.65	1	
٧ı	Input voltage	•	0	5.5	0	5.5	V	
٧o	Output voltage		0	Vcc	0	Vcc	V	
		V _{CC} = 2 V		-50		-50	μΑ	
ІОН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	T	-4 -4			A	
		$V_{CC} = 5 V \pm 0.5 V$	VCC = 3 V 2.1 VCC = 5.5 V 3.85 VCC = 2 V 0.5 VCC = 3 V 0.9 VCC = 5.5 V 1.65 0 VCC 0.5 VCC = 2 V -50 VCC = 3.3 V ± 0.3 V -4 VCC = 5 V ± 0.5 V -8 VCC = 3.3 V ± 0.3 V 4 VCC = 5 V ± 0.5 V 8 VCC = 3.3 V ± 0.3 V 100 VCC = 5 V ± 0.5 V 20	-8		-8	mA	
		V _{CC} = 2 V		50		50	μΑ	
lOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$				4	A	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
A+/A>.	land transition via a seful rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	20/1	
Δt/Δv	Input transition rise or fall rate			20		20	ns/V	
TA	Operating free-air temperature	-	-55	125	-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	Vaa	T,	ղ = 25°C	= 25°C		SN54AHC157		SN74AHC157	
FA	KAWIETEK	TEST CONDITIONS	vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	2		1.9		1.9		
		I _{OH} = -50 μA	3 V	2.9	3		2.9		2.9		
Voн			4.5 V	4.4	4.5		4.4		4.4		V
		I _{OH} = -4 mA	3 V	2.58			2.48		2.48		
		I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
						0.1		0.1		0.1	
		I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
VOL			4.5 V			0.1		0.1		0.1	V
		I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
		I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
П	A or B inputs	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
Icc	-	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
Ci		V _I = V _{CC} or GND	5 V		2	10				10	pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Δ = 25°(С	SN54A	HC157	SN74AI	HC157	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
t _{PLH}	A or B	Υ	C _L = 15 pF		6.2**	9.7**	1**	11.5**	1	11.5	ns	
^t PHL	AOIB		CL = 13 pr		6.2**	9.7**	1**	11.5**	1	11.5	115	
t _{PLH}	Ā/B	Y	C _I = 15 pF		8.4**	13.2**	1**	15.5**	1	15.5	ns	
t _{PHL}	A/B	ı	CL = 15 pr	OL = 13 pr		8.4**	13.2**	1**	15.5**	1	15.5	115
t _{PLH}	G	Υ	C _I = 15 pF		8.7**	13.6**	1**	16**	1	16	ns	
^t PHL		G	ľ	CL = 13 pr		8.7**	13.6**	1**	16**	1	16	115
t _{PLH}	A or B	Υ	C ₁ = 50 pF		8.7	13.2	1	15	1	15	ns	
t _{PHL}	AOIB	ı	CL = 30 pr		8.7	13.2	1	15	1	15	115	
t _{PLH}	A/B	Υ	C _I = 50 pF		10.9	16.7	1	19	1	19	ns	
tPHL	A/B	ſ	Ť	Т СС = 50 рг		10.9	16.7	1	19	1	19	115
t _{PLH}	G	Y	C: - 50 pE		11.2	17.1	1	19.5	1	19.5	ns	
t _{PHL}	G	ſ	C _L = 50 pF		11.2	17.1	1	19.5	1	19.5	118	

^{**} On products compliant to MIL-PRF-38535, this parameter is not production tested.

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T	Վ = 25° C	;	SN54AI	HC157	SN74AI	HC157	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT		
tPLH	A or B	Y	C _I = 15 pF		4.1*	6.4*	1*	7.5*	1	7.5	ns		
t _{PHL}	AOIB	'	GE = 13 bis		4.1*	6.4*	1*	7.5*	1	7.5	110		
tPLH	A/B	Y	C _I = 15 pF		5.3*	8.1*	1*	9.5*	1	9.5	ns		
t _{PHL}	A/B	Y	ī	i CL	CL = 15 pr		5.3*	8.1*	1*	9.5*	1	9.5	115
tPLH	ĪG	Y	C ₁ = 15 pF		5.6*	8.6*	1*	10*	1	10	ns		
t _{PHL}	G	'	CL = 15 pr		5.6*	8.6*	1*	10*	1	10	115		
t _{PLH}	A or B	Y	C 50 pF		5.6	8.4	1	9.5	1	9.5	no		
t _{PHL}	AUB	ī	C _L = 50 pF		5.6	8.4	1	9.5	1	9.5	ns		
tPLH		Y	C ₁ = 50 pF		6.8	10.1	1	11.5	1	11.5	ns		
t _{PLH}	A/B		T	, CL=;	CL = 30 pr		6.8	10.1	1	11.5	1	11.5	115
t _{PLH}	G	Y	C _L = 50 pF		7.1	10.6	1	12	1	12	ns		
^t PHL	9	1	GL = 30 pr		7.1	10.6	1	12	1	12	115		

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER		SN74AHC157			
	PARAMETER	MIN TYP MAX 0.8 -0.8	UNIT			
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}			0.8	V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}			-0.8	V	
VOH(V)	Quiet output, minimum dynamic VOH		4.8		V	
VIH(D)	High-level dynamic input voltage	3.5			V	
V _{IL(D)}	Low-level dynamic input voltage			1.5	V	

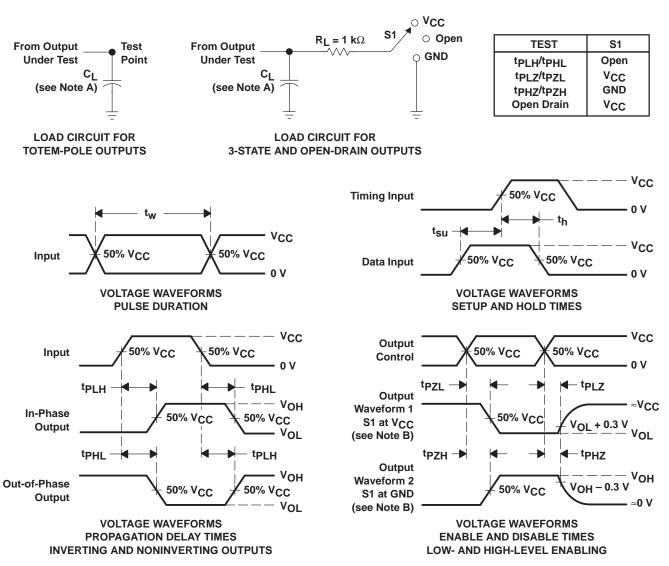
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER		ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	11	pF

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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